NSN 5961-01-061-3423

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-061-3423 **Inclosure Material:** Glass **Mounting Method:** Terminal **Features Provided:** Gold plated leads and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 forward voltage, peak **Current Rating Per Characteristic:** 1.00 microamperes forward current, average outside diameter **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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